
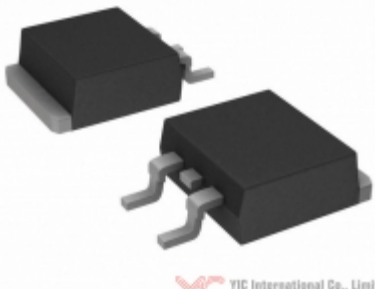





	<h2 style="color: red;">IRFBC40STRR</h2>
	<p>Manufacturer Part Number: IRFBC40STRR</p> <p>Manufacturer/Brand: Electro-Films (EFI) / Vishay</p> <p>Part of Description: MOSFET N-CH 600V 6.2A D2PAK</p> <p>Datasheets:  IRFBC40STRR.pdf</p> <p>RoHs Status: Contains lead / RoHS non-compliant</p> <p>Stock Condition: New original, 5000 pcs Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications

Part Number	IRFBC40STRR
Manufacturer	Electro-Films (EFI) / Vishay
Description	MOSFET N-CH 600V 6.2A D2PAK
Category	Discrete Semiconductor Products > Transistors - FETs ,
Part Status	5000 pcs Stock
Detailed Description	N-Channel 600V 6.2A (Tc) 3.1W (Ta), 130W (Tc)
Series	-
Technology	MOSFET (Metal Oxide)
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device Package	D2PAK
Power Dissipation (Max)	3.1W (Ta), 130W (Tc)
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	6.2A (Tc)
Rds On (Max) @ Id, Vgs	1.2 Ohm @ 3.7A, 10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1300pF @ 25V
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Packaging	Tape & Reel (TR)
Lead Free Status / RoHS Status	Contains lead / RoHS non-compliant
Moisture Sensitivity Level (MSL)	1 (Unlimited)




IRFBC40STRR is New Original in Stock, Search IRFBC40STRR Datasheets, PDF, Inventory at Y-IC.com Online, Order IRFBC40STRR Electro-Films (EFI) / Vishay with warranted and confidence. RFQ IRFBC40STRR : Info@Y-IC.com

You May Be Also Be interested In:

 <p>IRFBC40SPBF Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>IRFBC40STRLPBF Vishay / Siliconix MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>IRFBE20 Electro-Films (EFI) / Vishay MOSFET N-CH 800V 1.8A TO-220AB</p>	 <p>IRFBE20 Vishay / Siliconix MOSFET N-CH 800V 1.8A TO-220AB</p>
 <p>IRFBC40STRL Vishay / Siliconix MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>IRFBC40STRL Electro-Films (EFI) / Vishay MOSFET N-CH 600V 6.2A D2PAK</p>	 <p>IRFBE20L Vishay / Siliconix MOSFET N-CH 800V 1.8A TO-262</p>	 <p>IRFBC41LC IR IRFBC41LC IR</p>

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 IRFBC40AS	 IRFBC40ASPBF	 IRFBC40ASPBF	 IRFBC40ASTRRPBF	 IRFBC40ASTRRPBF
 IRFBC40F	 IRFBC40LC	 IRFBC40LC	 IRFBC40LCPBF	 IRFBC40LCPBF
 IRFBC40LPBF	 IRFBC40LPBF	 IRFBC40S	 IRFBC40S	 IRFBC40SPBF
 IRFBC40SPBF	 IRFBC40STRL	 IRFBC40STRL	 IRFBC40STRLPBF	 IRFBC40STRLPBF
 IRFBC40STRR	 IRFBC41LC	 IRFBE20PBF	 IRFBE20PBF	 IRFBE20SPBF
 IRFBE30L	 IRFBE30L	 IRFBE30LPBF-M	 IRFBE30PBF	 IRFBE30PBF
 IRFBE30SPBF	 IRFBE30SPBF	 IRFBE30STRLPBF	 IRFBE30STRLPBF	 IRFBF20LPBF
 IRFBF20LPBF	 IRFBF20STRL	 IRFBF20STRL	 IRFBF20STRLPBF	 IRFBF20STRLPBF
 IRFBG20PBF	 IRFBG20PBF	 IRFBG30PBF	 IRFBG30PBF	 IRFBL10N60A

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